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438	Subclass
517	Class
ISSUE CLASSIFICATION	

U.S. UTILITY Patent Application

SCANNED

J.P.E

D.A.

PATENT DATE

APPLICATION NO.
09/670520

CONT/PRIOR
F

CLASS
438

SUBCLASS
517

ART UNIT
2812

EXAMINER G Lee
~~Dr. S. J. ...~~

Wakako Moriyama
Naoki Kai
Hiroaki Hazama
Keiki Nagai

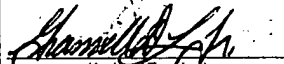
Method for manufacturing semiconductor devices using thermal nitride films as gate insulating films

PTO-2040
12/89

ISSUING CLASSIFICATION

ORIGINAL			CROSS REFERENCE(S)						
CLASS		SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)					
438		519	438	517	195	201	591	593	769
INTERNATIONAL CLASSIFICATION			257	314	331				
401	L	211425							

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<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg. 31	Figs. Drwg. 44	Print Fig. 5F & 6	Total Claims: 15	Print Claim for O.G. 1
<input checked="" type="checkbox"/> The term of this patent subsequent to _____ (date) has been disclaimed.	 (Assistant Examiner)			NOTICE OF ALLOWANCE MAILED	
<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S. Patent. No. _____	_____ (Primary Examiner)			ISSUE FEE	
	_____ (Date)			Amount Due	Date Paid
<input type="checkbox"/> The terminal _____ months of this patent have been disclaimed.	_____ (Legal Instruments Examiner)			ISSUE BATCH NUMBER	
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